# AO4824/MC4824

## Freescale

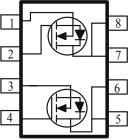
# Dual N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r<sub>DS(on)</sub> provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	r <sub>DS(on)</sub> m(Ω)	I <sub>D</sub> (A)		
30	$13.5 @ V_{GS} = 10V$	10		
	$20 @ V_{GS} = 4.5V$	8		





ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage		V <sub>DS</sub>	30	V	
Gate-Source Voltage		V <sub>GS</sub>	±20	v	
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =25°C	т	10		
	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	ID	8.2	А	
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	±50		
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	2.3	А	
	T <sub>A</sub> =25°C	P <sub>D</sub>	2.1	W	
Power Dissipation <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	1 D	D 1.3		
Operating Junction and Storage Temperature Range			-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
Maximum Junction-to-Case <sup>a</sup>	t <= 5 sec	$R_{\theta JC}$	40	°C/W	
Maximum Junction-to-Ambient <sup>a</sup>	t <= 5 sec	$R_{\theta JA}$	60	°C/W	

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Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

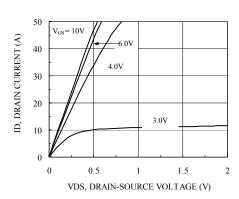
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SPECIFICATIONS ( $T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)							
Parameter		Limits			Unit		
rarameter	Symbol	Symbol Test Conditions		Тур	Max	Unit	
Static							
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 V, I_D = 250 uA$	30			v	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	1			v	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = 20 V$			±100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 24 V, V_{GS} = 0 V$			1	uA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 24 V, V_{GS} = 0 V, T_J = 55^{\circ}C$			25		
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 V, V_{GS} = 10 V$	20			Α	
		$V_{GS} = 10 \text{ V}, I_D = 10 \text{ A}$			13.5		
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 8 \text{ A}$			20	mΩ	
		$V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}, T_J = 55^{\circ}\text{C}$			15		
Forward Tranconductance <sup>A</sup>	$g_{fs}$	$V_{DS} = 15 \text{ V}, I_D = 10 \text{ A}$		40		S	
Diode Forward Voltage	V <sub>SD</sub>	$I_{\rm S} = 2.3$ A, $V_{\rm GS} = 0$ V		0.7		V	
Pulsed Source Current (Body Diode) <sup>A</sup>	I <sub>SM</sub>			5		Α	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg	$V_{DS} = 15 V, V_{GS} = 5 V,$		20			
Gate-Source Charge	Q <sub>gs</sub>	$v_{DS} = 15 v, v_{GS} = 5 v,$ $I_D = 10 A$		7.0		nC	
Gate-Drain Charge	Q <sub>gd</sub>	$I_D = 10 \text{ A}$		7.0			
Turn-On Delay Time	t <sub>d(on)</sub>			20			
Rise Time	t <sub>r</sub>	$V_{DD}$ = 25 V, $R_L$ = 25 $\Omega$ , $I_D$ = 1 A,		9		nS	
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{\text{GEN}} = 10 \text{ V}$		70		115	
Fall-Time	t <sub>f</sub>			20			

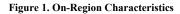
Notes

- a. Pulse test:  $PW \le 300$ us duty cycle  $\le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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Typical Electrical Characteristics (N-Channel)



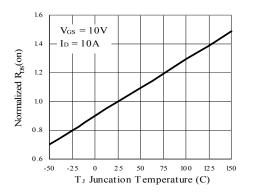


Figure 3. On-Resistance Variation with Temperature

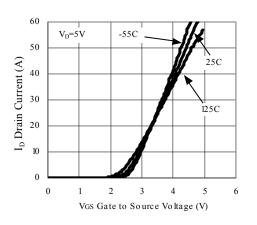


Figure 5. Transfer Characteristics

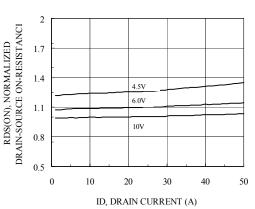


Figure 2. On-Resistance with Drain Current

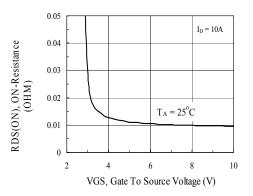
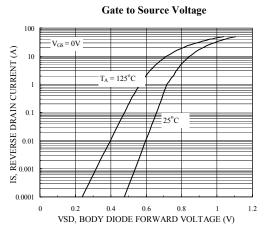
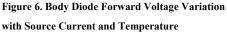
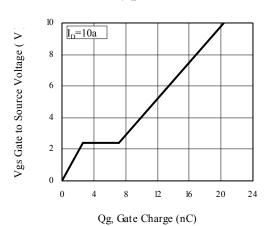


Figure 4. On-Resistance Variation with

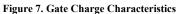




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Typical Electrical Characteristics (N-Channel)



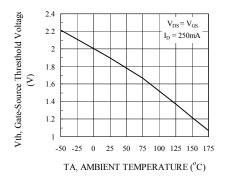


Figure 9. Threshold Vs Ambient Temperature

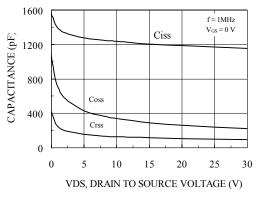


Figure 8. Capacitance Characteristics

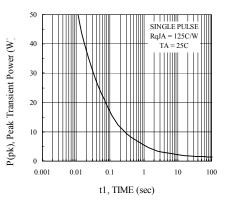


Figure 10. Single Pulse Maximum Power Dissipation

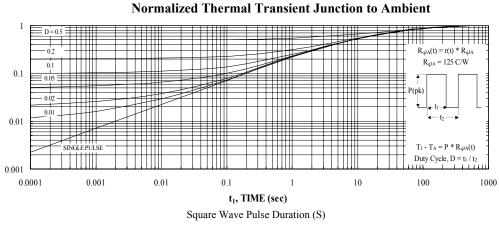
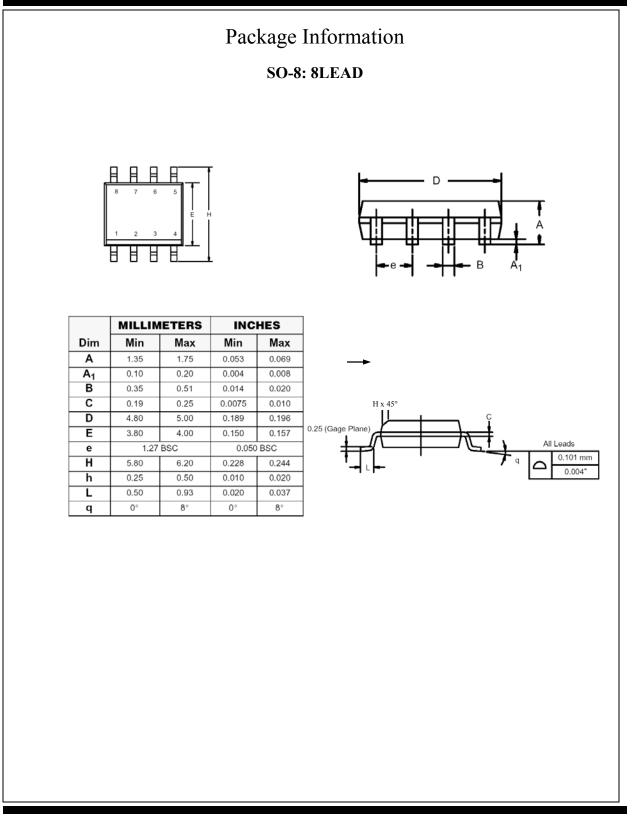


Figure 11. Transient Thermal Response Curve

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# Ordering information

- AM4910N-T1-XX
  - A: Analog Power
  - M: MOSFET
  - 4910: Part number
  - N: N-Channel
  - T1: Tape & reel
  - XX: Blank: StandardPF: Leadfree

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